

## BIDIRECTIONAL INPUT DARLINGTON OPTOCOUPLEDERS

### FEATURES

- Internal  $R_{BE}$  for Better Stability
- High Current Transfer Ratios,  $V_{CE}=5\text{ V}$   
IL/ILD766-1: 500% at  $I_F=2\text{ mA}$   
IL/ILD766-2: 500% at  $I_F=1.0\text{ mA}$
- $BV_{CEO} > 80\text{ V}$
- AC or Polarity Insensitive Inputs
- Built-In Reverse Polarity Input Protection
- Industry Standard DIP Package
- Underwriters Lab File #E52744

### DESCRIPTION

The IL/ILD766 are bidirectional input optically coupled isolators. They consist of two Gallium Arsenide infrared emitting diodes coupled to a silicon NPN photodarlington per channel.

The IL766 are single channel optocouplers. The ILD766 has two isolated channels in a single DIP package. They are designed for applications requiring detection or monitoring of AC signals.

### Maximum Ratings

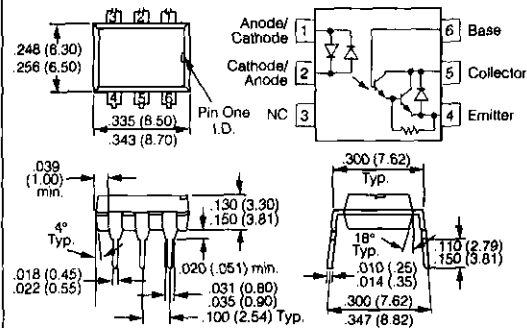
|                                           |            |
|-------------------------------------------|------------|
| <b>Emitter (Each Channel)</b>             |            |
| Continuous Forward Current .....          | 60 mA      |
| Power Dissipation at 25°C                 |            |
| Single Channel .....                      | 200 mW     |
| Dual Channel .....                        | 90 mW      |
| Derate Linearly from 25°C                 |            |
| Single Channel .....                      | 2.6 mW/°C  |
| Dual Channel .....                        | 1.2 mW/°C  |
| <b>Detector (Each Channel)</b>            |            |
| Collector-Emitter Breakdown Voltage ..... | 60 V       |
| Collector-Base Breakdown Voltage .....    | 70 V       |
| Power Dissipation at 25°C .....           | 100 mW     |
| Derate Linearly from 25°C .....           | 1.33 mW/°C |

### Package

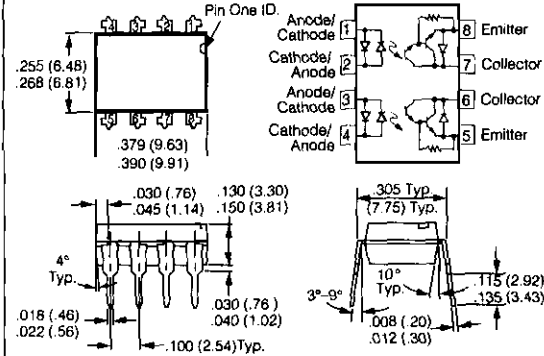
|                                                |                                                 |
|------------------------------------------------|-------------------------------------------------|
| <b>Isolation Test Voltage</b>                  |                                                 |
| ( $t = 1\text{ sec.}$ ) .....                  | 7500 VAC <sub>PK</sub> /5300 VAC <sub>RMS</sub> |
| <b>Isolation Resistance</b>                    |                                                 |
| $T_A=25^\circ\text{C}$ .....                   | $\geq 10^{12}\ \Omega$                          |
| $T_A=100^\circ\text{C}$ .....                  | $\geq 10^{11}\ \Omega$                          |
| <b>Total Power Dissipation at 25°C Ambient</b> |                                                 |
| (LED Plus Detector)                            |                                                 |
| Single Channel .....                           | 250 mW                                          |
| Dual Channel .....                             | 400 mW                                          |
| Derate Linearly from 25°C                      |                                                 |
| Single Channel .....                           | 3.3 mW/°C                                       |
| Dual Channel .....                             | 5.3 mW/°C                                       |
| Creepage .....                                 | 7 mm min.                                       |
| Clearance .....                                | 7 mm min.                                       |
| Comparative Tracking Index per                 |                                                 |
| DIN IEC 112/VDE303, part 1 .....               | 175                                             |
| Storage Temperature .....                      | -55°C to +150°C                                 |
| Operating Temperature .....                    | -55°C to +100°C                                 |
| Lead Soldering Time at 260°C .....             | 10 sec.                                         |

### Package Dimensions in Inches (mm)

#### Single Channel



#### Dual Channel



### Electrical Characteristics ( $T_A=25^\circ\text{C}$ )

|                      | Symbol     | Min. | Typ. | Max. | Unit          | Condition                                                              |
|----------------------|------------|------|------|------|---------------|------------------------------------------------------------------------|
| <b>Emitter</b>       |            |      |      |      |               |                                                                        |
| Forward Voltage      | $V_F$      |      | 1.2  | 1.5  | V             | $I_F=\pm 10\text{ mA}$                                                 |
| <b>Detector</b>      |            |      |      |      |               |                                                                        |
| Breakdown Voltage    |            |      |      |      |               |                                                                        |
| Collector-Emitter    | $BV_{CEO}$ | 60   | 75   |      | V             | $I_C=1\text{ mA}$                                                      |
| Collector-Base       | $BV_{CBO}$ | 60   | 90   |      | V             | $I_C=10\ \mu\text{A}$                                                  |
| Leakage Current      |            |      |      |      |               |                                                                        |
| Collector-Emitter    | $I_{CEO}$  |      | 10   | 100  | nA            | $V_{CE}=10\text{ V}$                                                   |
| <b>Package</b>       |            |      |      |      |               |                                                                        |
| $V_{CESat}$          |            |      |      | 1.0  | V             | $I_F=\pm 10\text{ mA}$ ,<br>$I_C=10\text{ mA}$                         |
| <b>DC Current</b>    |            |      |      |      |               |                                                                        |
| Transfer Ratio       | CTR        |      |      |      | %             |                                                                        |
| IL766/ILD766-1       |            | 500  |      |      | %             | $I_F=\pm 2\text{ mA}$ ,<br>$V_{CE}=5\text{ V}$                         |
| IL766-2              |            | 500  |      |      | %             | $I_F=\pm 1.0\text{ mA}$ ,<br>$V_{CE}=5\text{ V}$                       |
| Rise Time, Fall Time |            |      | 100  |      | $\mu\text{s}$ | $V_{CC}=10\text{ V}$ ,<br>$I_F=\pm 2\text{ mA}$ ,<br>$R_L=100\ \Omega$ |

Optocouplers  
(Transistors)

Figure 1. Input characteristics

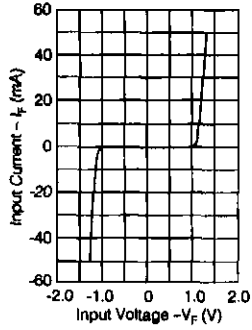


Figure 2. Transistor current versus voltage

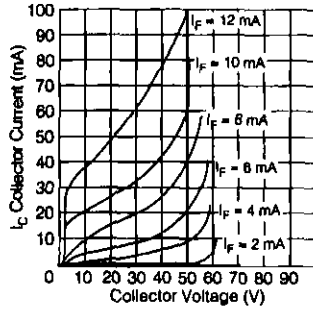


Figure 3. Transistor output current versus voltage

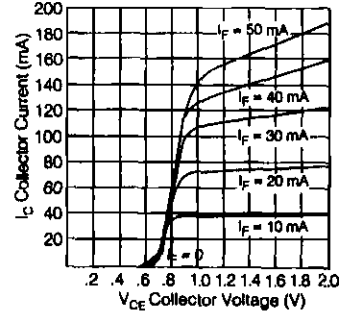


Figure 4.  $I_{CE0}$  at  $V_{CE}=10$  V versus temperature

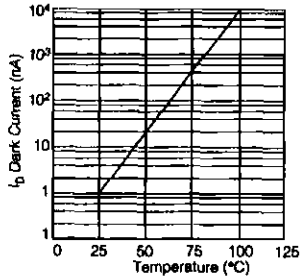


Figure 5. Normalized CTR versus forward current

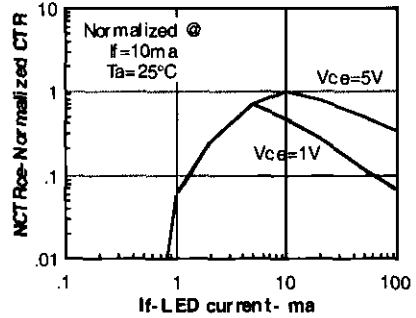


Figure 6.  $T_r$  versus forward current

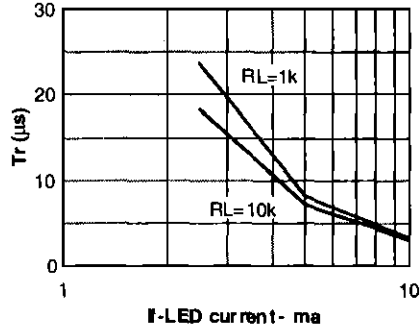


Figure 7. Saturated switching characteristics measurements—schematic and waveform

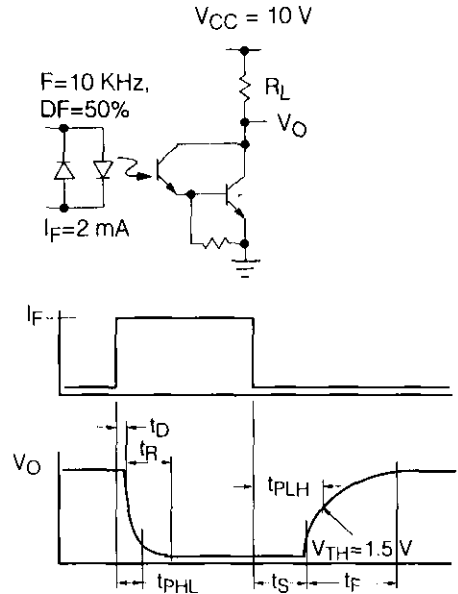


Figure 8. Tfall versus forward current

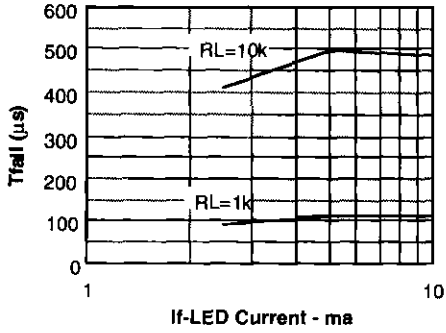


Figure 9. Ton versus forward current

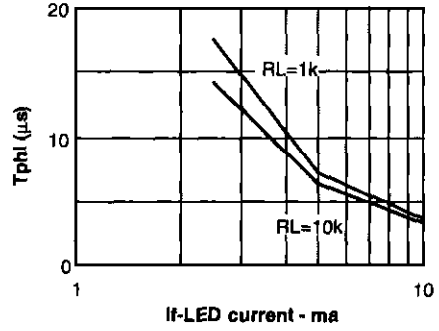


Figure 10. Toff versus forward current

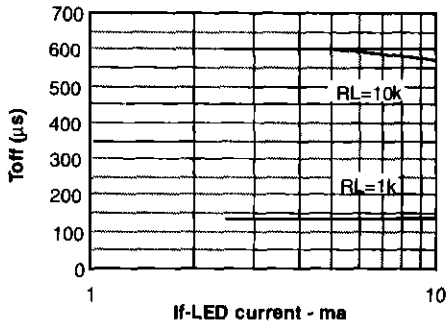


Figure 11. Tphi versus forward current

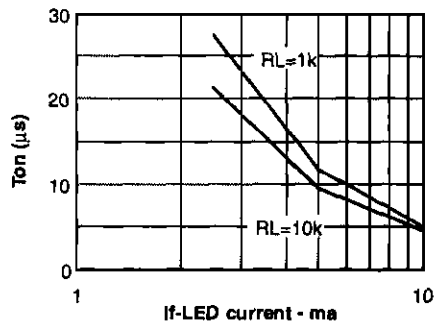


Figure 12. Tphi versus forward current

